Low-Voltage CMOS **16-Bit Buffer**

With 5 V-Tolerant Inputs and Outputs (3-State, Inverting)

The MC74LCX16240 is a high performance, inverting 16-bit buffer operating from a 2.3 V to 3.6 V supply. The device is nibble controlled. Each nibble has separate Output Enable inputs which can be tied together for full 16-bit operation. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows MC74LCX16240 inputs to be safely driven from 5.0 V devices. The LCX16240 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

Current drive capability is 24 mA at the outputs. The Output Enable (OEn) inputs, when HIGH, disable the outputs by placing them in a HIGH Z condition.

The MC74LCX16240 contains sixteen inverting buffers with 3-state 5.0 V tolerant outputs. The device is nibble controlled with each nibble functioning identically, but independently. The control pins may be tied together to obtain full 16-bit operation. The 3-state EFORINF outputs are controlled by an Output Enable (OEn) input for each nibble. When \overline{OEn} is LOW, the outputs are on. When \overline{OEn} is HIGH, the outputs are in the high impedance state.

Features

- Designed for 2.3 to 3.6 V V_{CC} Operation
- 5.0 V Tolerant Interface Capability With 5.0 V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When $V_{CC} = 0 \text{ V}$
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- ESD Performance: Human Body Model >2000 V;

Machine Model >200 V

• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

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TSSOP-48 DT SUFFIX CASE 1201

MARKING DIAGRAM



= Assembly Location

WI = Wafer Lot ΥY = Year WW = Work Week = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

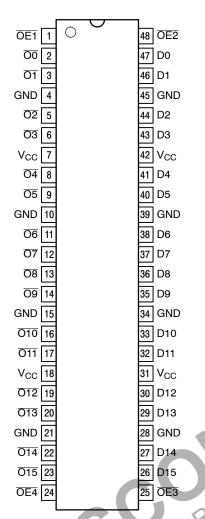


Table 1. PIN NAMES

Pins	Function
OEn	Output Enable Inputs
D0-D15	Inputs
O0-O15	Outputs

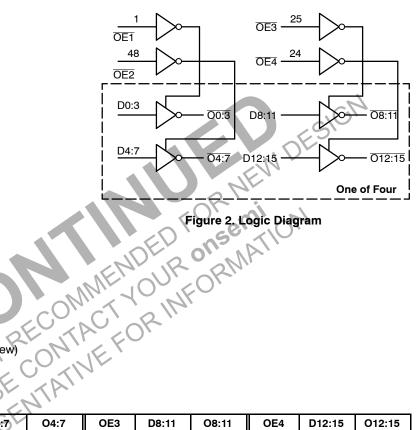


Figure 1. Pinout: TSSOP-48 (Top View)

TRUTH TABLE

OE1	D0:3	O0:3	OE2	D4:7	04:7	OE3	D8:11	O8:11	OE4	D12:15	O12:15
L	L	Н	LO	77	Н	L	L	Н	L	L	Н
L	NB Y	L	QK,	Н	L	L	Н	L	L	Н	L
н	X	Z	Н	Х	Z	Н	Х	Z	Н	Х	Z

H L Z X High Voltage Level Low Voltage Level High Impedance State

High or Low Voltage Level and Transitions are Acceptable; for I_{CC} reasons, DO NOT FLOAT Inputs

ORDERING INFORMATION

Device	Package	Shipping [†]
M74LCX16240DTR2G	TSSOP-48 (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Symbol	Parameter	Value	Condition	Unit
V _{CC}	DC Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	$-0.5 \le V_{I} \le +7.0$		V
Vo	DC Output Voltage	$-0.5 \le V_0 \le +7.0$	Output in 3-State	V
		$-0.5 \le V_O \le V_{CC} + 0.5$	Output in HIGH or LOW State (Note 1)	V
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA
I _{OK}	DC Output Diode Current	-50	V _O < GND	mA
		+50	V _O > V _{CC}	mA
I _O	DC Output Source/Sink Current	±50	O S Mr	mA
I _{CC}	DC Supply Current Per Supply Pin	±100	50 mi N	mA
I _{GND}	DC Ground Current Per Ground Pin	±100	0, 66, (0)	mA
T _{STG}	Storage Temperature Range	-65 to +150	ONIA	°C
MSL	Moisture Sensitivity		Level 1	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage Operating Data Retention Only	2.0 1.5	2.5, 3.3 2.5, 3.3	3.6 3.6	٧
VI	Input Voltage	0		5.5	V
Vo	Output Voltage (HIGH or LOW State) (3-State)	0		V _{CC} 5.5	٧
ІОН	HIGH Level Output Current $ \begin{array}{c} V_{CC} = 3.0 \ V - 3.6 \ V \\ V_{CC} = 2.7 \ V - 3.0 \ V \\ V_{CC} = 2.3 \ V - 2.7 \ V \end{array} $			-24 -12 -8	mA
l _{OL}	LOW Level Output Current $ \begin{array}{c} V_{CC} = 3.0 \ V - 3.6 \ V \\ V_{CC} = 2.7 \ V - 3.0 \ V \\ V_{CC} = 2.3 \ V - 2.7 \ V \\ \end{array} $			+24 +12 +8	mA
T _A	Operating Free-Air Temperature	-40		+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate, V_{IN} from 0.8 V to 2.0 V, V_{CC} = 3.0 V	0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

			T _A = -40°0	C to +85°C	
Symbol	Characteristic	Condition	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage (Note 2)	$2.3 \text{ V} \le \text{V}_{CC} \le 2.7 \text{ V}$	1.7		V
		$2.7 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}$	2.0		
V_{IL}	LOW Level Input Voltage (Note 2)	$2.3 \text{ V} \le \text{V}_{CC} \le 2.7 \text{ V}$		0.7	V
		$2.7 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}$		0.8	
V _{OH}	HIGH Level Output Voltage	$2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; \text{I}_{OL} = 100 \mu\text{A}$	V _{CC} - 0.2		V
		V _{CC} = 2.3 V; I _{OH} = -8 mA	1.8		
		$V_{CC} = 2.7 \text{ V}; I_{OH} = -12 \text{ mA}$	2.2		
		$V_{CC} = 3.0 \text{ V}; I_{OH} = -18 \text{ mA}$	2.4		
		$V_{CC} = 3.0 \text{ V}; I_{OH} = -24 \text{ mA}$	2.2		
V _{OL}	LOW Level Output Voltage	$2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; \text{I}_{OL} = 100 \mu\text{A}$		0.2	V
		V _{CC} = 2.3 V; I _{OL} = 8 mA		0.6	
		V _{CC} = 2.7 V; I _{OL} = 12 mA		0.4	
		V _{CC} = 3.0 V; I _{QL} = 16 mA	IN	0.4	
		V _{CC} = 3.0 V; I _{OL} = 24 mA	TE.	0.55	
l _{OZ}	3-State Output Current	$V_{CC} = 3.6 \text{ V}, V_{IN} = V_{IH} \text{ or } V_{IL},$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$	mi or	±5	μΑ
I _{OFF}	Power Off Leakage Current	$V_{CC} = 0$, $V_{IN} = 5.5 \text{ V or } V_{OUT} = 5.5 \text{ V}$	1/10	10	μΑ
I _{IN}	Input Leakage Current	V _{CC} = 3.6 V, V _{IN} = 5.5 V or GND	VIV.	±5	μΑ
I _{CC}	Quiescent Supply Current	$V_{CC} = 3.6 \text{ V}, V_{IN} = 5.5 \text{ V} \text{ or GND}$		10	μΑ
ΔI_{CC}	Increase in I _{CC} per Input	$2.3 \le V_{CC} \le 3.6 \text{ V}; V_{IH} = V_{CC} - 0.6 \text{ V}$		500	μА

^{2.} These values of V_I are used to test DC electrical characteristics only.

AC CHA	AC CHARACTERISTICS $t_R = t_F = 2.5 ns$; $R_L = 500 \Omega$								
	19	CE			T _A = -40°C	C to +85°C			
	ICE	EASE	V _{CC} = 3.3 C _L =	V ± 0.3 V 50 pF	V _{CC} =		V _{CC} = 2.5 C _L =	V ± 0.2 V 30 pF	
Symbol	Parameter	Waveform	Min	Max	Min	Max	Min	Max	Unit
t _{PLH}	Propagation Delay Input to Output	1	1.5 1.5	4.5 4.5	1.5 1.5	5.3 5.3	1.5 1.5	5.4 5.4	ns
t _{PZH}	Output Enable Time to High and Low Level	2	1.5 1.5	5.4 5.4	1.5 1.5	6.0 6.0	1.5 1.5	7.0 7.0	ns
t _{PHZ}	Output Disable Time From High and Low Level	2	1.5 1.5	5.3 5.3	1.5 1.5	5.4 5.4	1.5 1.5	6.4 6.4	ns
t _{OSHL} t _{OSLH}	Output-to-Output Skew (Note 3)			1.0 1.0					ns

^{3.} Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (toSHL) or LOW-to-HIGH (toSLH); parameter guaranteed by design.

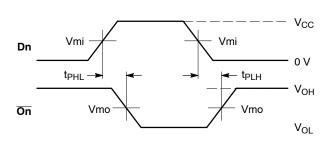
DYNAMIC SWITCHING CHARACTERISTICS

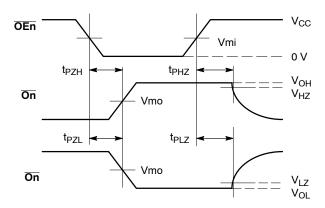
			T _A = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
V _{OLP}	Dynamic LOW Peak Voltage (Note 4)	$V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ $V_{CC} = 2.5 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$		0.8 0.6		V V
V _{OLV}	Dynamic LOW Valley Voltage (Note 4)	$V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ $V_{CC} = 2.5 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$		-0.8 -0.6		V

^{4.} Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	7	pF
C _{OUT}	Output Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	10 MHz, V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	20	pF
	C C IS NO ENCE PLE	OR CONNENDED FOR THE CONTROL OF RECONTACT FOR INFORMATION OF THE PROPERTY OF T	REN DES,	





WAVEFORM 1 - PROPAGATION DELAYS $t_R = t_F = 2.5 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$

WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES $t_R = t_F = 2.5 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$

Figure 3. AC Waveforms

Table 2. AC WAVEFORMS

	Figure 3. AC Waveforms	
Table 2. AC WAVEFO	BMS NDESIGN	
Table 2. AO WAVEL O		
	V _{cc}	
Symbol	3.3 V ± 0.3 V 2.7 V 2.5 V ± 0.2 V	
Vmi	1.5 V 1.5 V V _{CC} /2	
Vmo	1.5 V 1.5 V V _{CC} \ 2	
V_{HZ}	V _{OL} + 0.3 V V _{OL} + 0.3 V V _{OL} + 0.15 V	
V_{LZ}	V _{OH} – 0.3 V V _{OH} – 0.3 V	

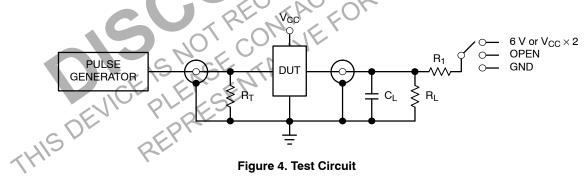


Figure 4. Test Circuit

Table 3. TEST CIRCUIT

TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	6 V at V $_{CC}$ = 3.3 \pm 0.3 V 6 V at V $_{CC}$ = 2.5 \pm 0.2 V
Open Collector/Drain t _{PLH} and t _{PHL}	6 V
t _{PZH} , t _{PHZ}	GND

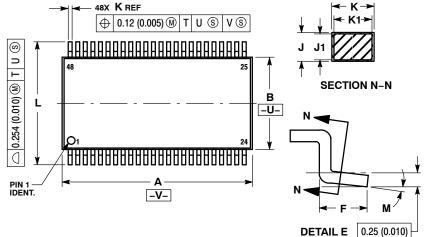
 C_L = 50 pF at V_{CC} = 3.3 \pm 0.3 V or equivalent (includes jig and probe capacitance) C_L = 30 pF at V_{CC} = 2.5 \pm 0.2 V or equivalent (includes jig and probe capacitance) R_L = R_1 = 500 Ω or equivalent

 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)



TSSOP-48 CASE 1201-01 ISSUE B

DATE 06 JUL 2010

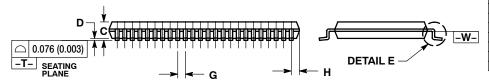




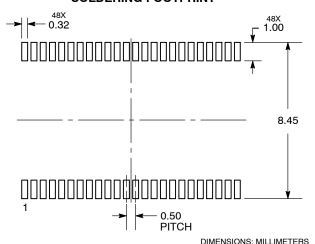
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 - DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS
- SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

 4. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- DIMENSIONS A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	12.40	12.60	0.488	0.496	
В	6.00	6.20	0.236	0.244	
С		1.10		0.043	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.50	BSC	0.019	7 BSC	
Н	0.37		0.015		
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.17	0.27	0.007	0.011	
K1	0.17	0.23	0.007	0.009	
L	7.95	8.25	0.313	0.325	
М	0 °	8°	0 °	8°	



RECOMMENDED SOLDERING FOOTPRINT



GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code

= Assembly Location

= Wafer Lot WL ΥY = Year ww = Work Week

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking.

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